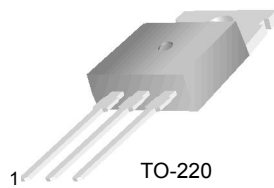


# KSC5021

## NPN Silicon Transistor

- High Voltage and High Reliability
- High Speed Switching :  $t_F = 0.1\mu s$  (Typ.)
- Wide SOA



TO-220

1.Base 2.Collector 3.Emitter

### Absolute Maximum Ratings $T_C = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	800	V
$V_{CEO}$	Collector-Emitter Voltage	500	V
$V_{EBO}$	Emitter-Base Voltage	7	V
$I_C$	Collector Current (DC)	5	A
$I_{CP}$	Collector Current (Pulse)	10	A
$I_B$	Base Current	2	A
$P_C$	Collector Dissipation ( $T_C=25^\circ C$ )	50	W
$T_J$	Junction Temperature	150	$^\circ C$
$T_{STG}$	Storage Temperature	- 55 ~ 150	$^\circ C$

**Electrical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted

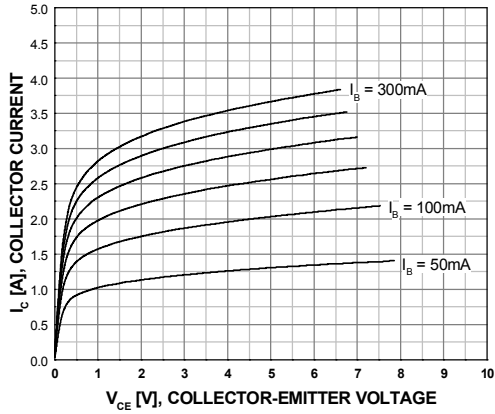
Symbol	Parameter	Conditions	Min.	Typ.	Max	Units
$BV_{CBO}$	Collector-Base Breakdown Voltage	$I_C = 1\text{mA}, I_E = 0$	800			V
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 5\text{mA}, I_B = 0$	500			V
$BV_{EBO}$	Emitter-Base Breakdown Voltage	$I_E = 1\text{mA}, I_C = 0$	7			V
$V_{CEX(sus)}$	Collector-Emitter Sustaining Voltage	$I_C = 2.5\text{A}, I_{B1} = -I_{B2} = 1\text{A}$ $L = 1\text{mH}, \text{Clamped}$	500			V
$I_{CBO}$	Collector Cut-off Current	$V_{CB} = 500\text{V}, I_E = 0$			10	$\mu\text{A}$
$I_{EBO}$	Emitter Cut-off Current	$V_{EB} = 5\text{V}, I_C = 0$			10	$\mu\text{A}$
$h_{FE1}$ $h_{FE2}$	DC Current Gain	$V_{CE} = 5\text{V}, I_C = 0.6\text{A}$ $V_{CE} = 5\text{V}, I_C = 3\text{A}$	15 8		50	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 3\text{A}, I_B = 0.6\text{A}$			1	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 3\text{A}, I_B = 0.6\text{A}$			1.5	V
$C_{ob}$	Output Capacitance	$V_{CB} = 10\text{V}, I_E = 0, f=1\text{MHz}$		80		pF
$f_T$	Current Gain Bandwidth Product	$V_{CE} = 10\text{V}, I_C = 0.6\text{A}$		18		MHz
$t_{ON}$	Turn On Time	$V_{CC} = 200\text{V}$ $I_C = 5I_{B1} = -2.5I_{B2} = 4\text{A}$ $R_L = 50\Omega$			0.5	$\mu\text{s}$
$t_{STG}$	Storage Time				3	$\mu\text{s}$
$t_F$	Fall Time				0.3	$\mu\text{s}$

\* Pulse Test:  $PW \leq 300\mu\text{s}$ , Duty Cycle  $\leq 2\%$  **$h_{FE}$  Classification**

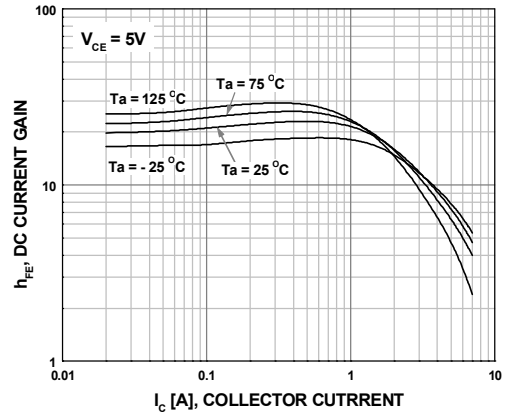
Classification	R	O	Y
$h_{FE1}$	15 ~ 30	20 ~ 40	30 ~ 50

## Typical Performance Characteristics

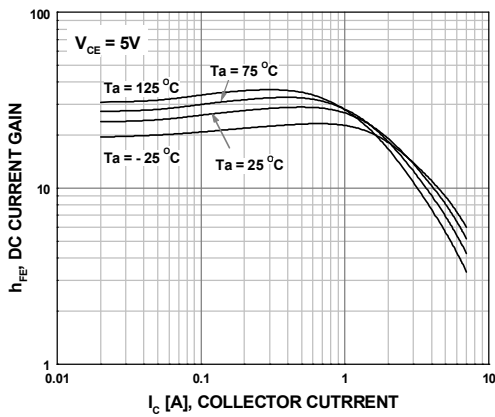
**Figure 1. Static Characteristic**



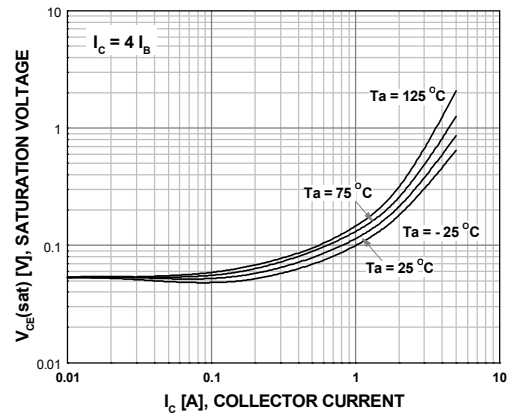
**Figure 2. DC Current Gain (R-Grade)**



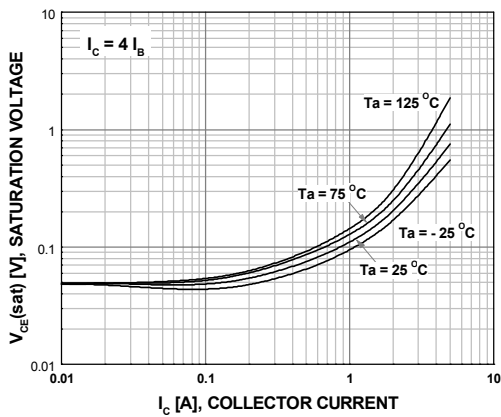
**Figure 3. DC Current Gain (O-Grade)**



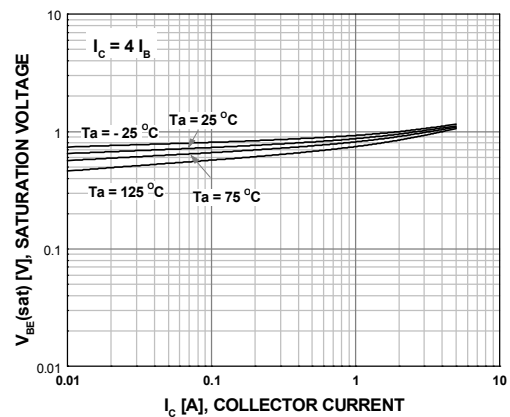
**Figure 4. Saturation Voltage (R-Grade)**



**Figure 5. Saturatin Voltage (O-Grade)**



**Figure 6. Saturation Voltage (R-Grade)**



# Typical Characteristics

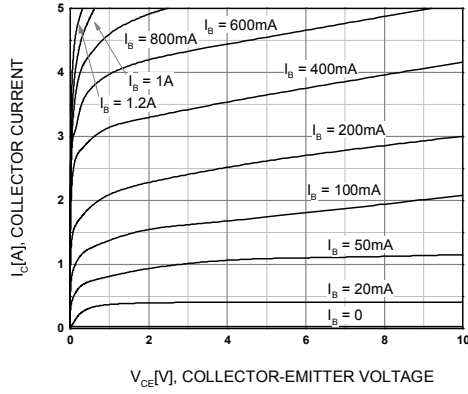


Figure 1. Static Characteristic

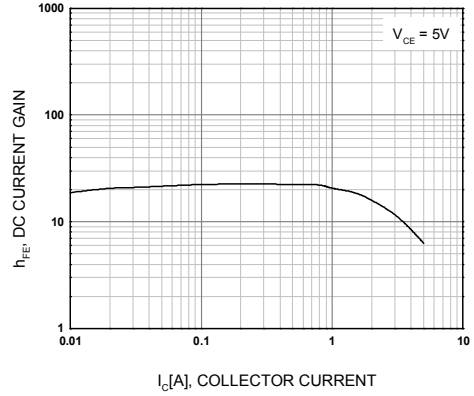


Figure 2. DC current Gain

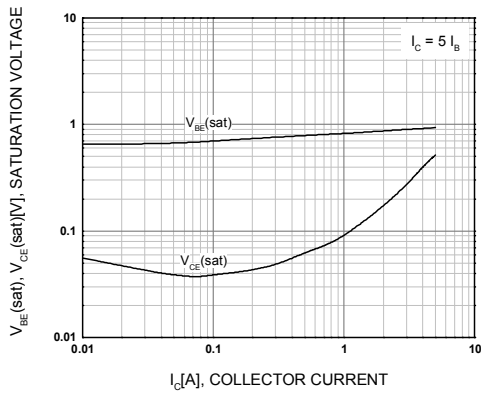


Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

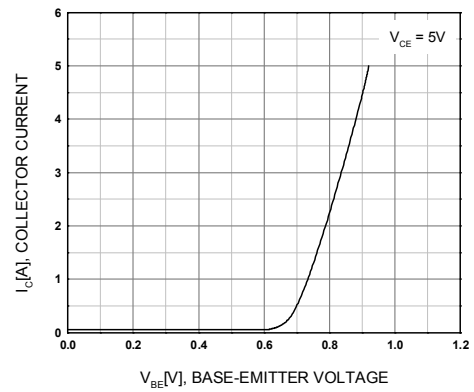


Figure 4. Base-Emitter On Voltage

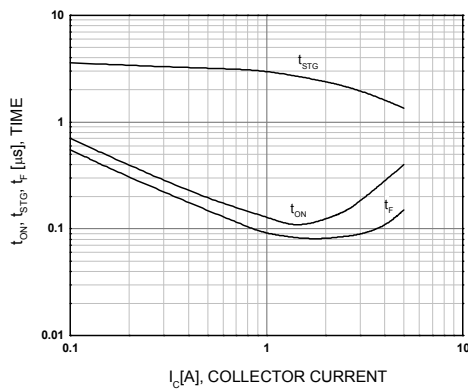


Figure 5. Switching Time

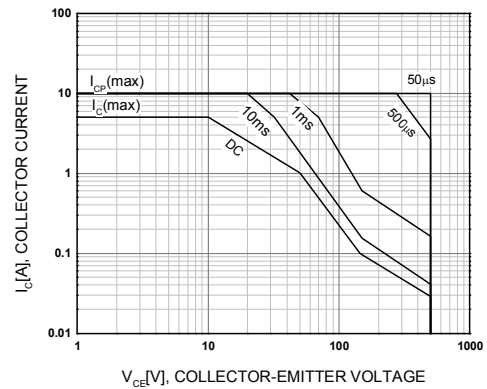


Figure 6. Safe Operating Area

Typical Characteristics (Continued)

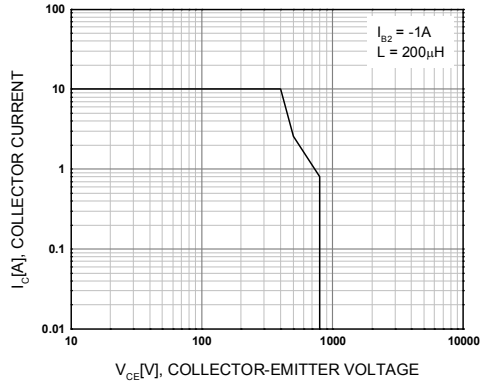


Figure 7. Reverse Bias Safe Operating Area

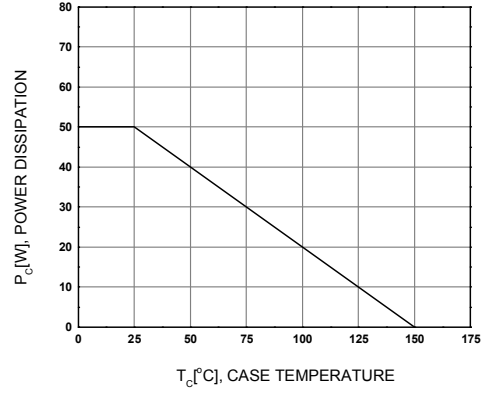
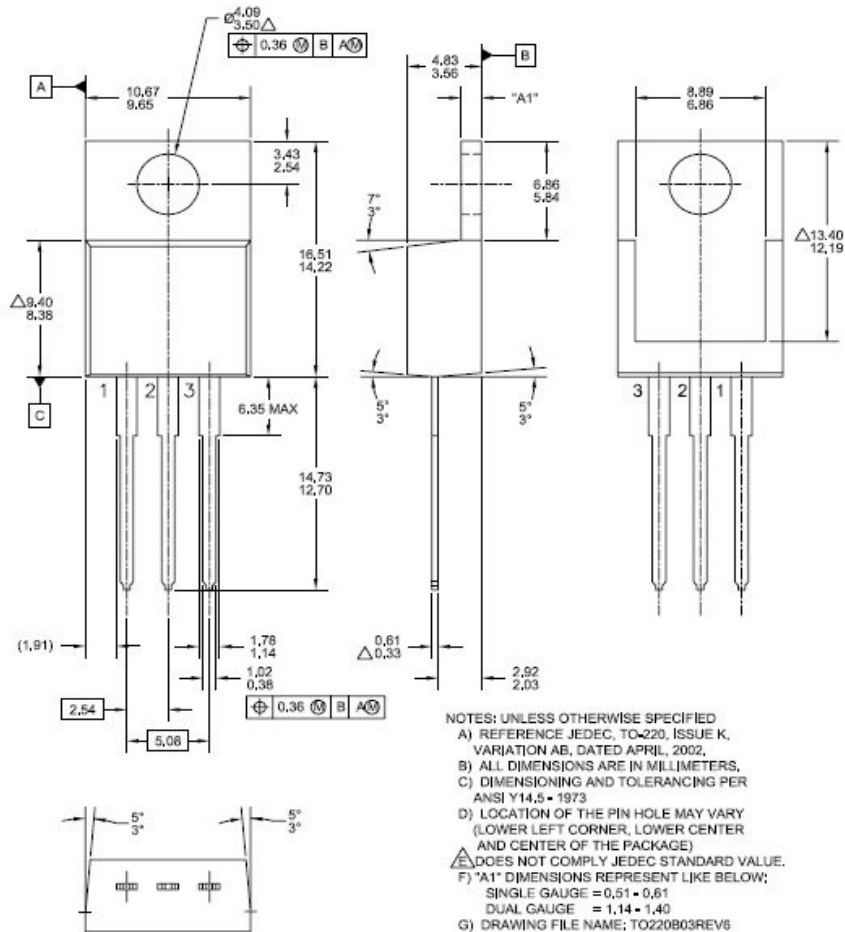


Figure 8. Power Derating

# Package Dimension

## TO-220

Dimensions are in mm



Dimensions in Millimeters



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FRFET®	 ®	SuperSOT™-3	VCX™
Global Power Resource <sup>SM</sup>	PDP-SPM™	SuperSOT™-6	
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